

/ Descriptions

Ultrafast Recovery Diode in a TO-220AC Plastic Package.

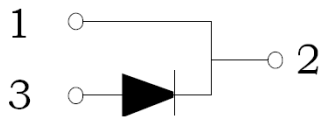
/ Features

Silicon epitaxial process to produce ultrafast recovery diode with low reverse leakage current and high reliability.

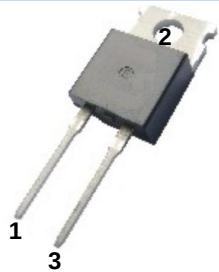
/ Applications

For high frequency, high voltage, high current rectifier diode, freewheeling diode.

/ Equivalent Circuit



/ Pinning



PIN1 2 Cathode

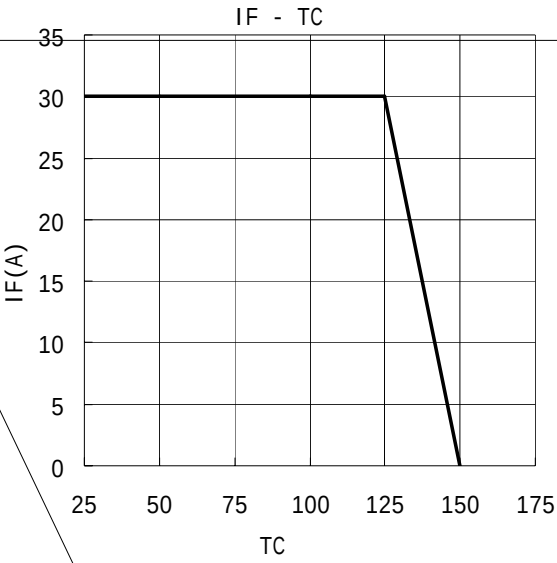
PIN 3 Anode

/ h_{FE} Classifications & Marking

See Marking Instructions

Parameter	Symbol	Rating	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	600	V
RMS Voltage	V_{RMS}	420	V
DC Blocking Voltage	V_{DC}	600	V
Maximum Average Forward Current	I_F	1 × 30	A
Peak forward surge current	I_{FSM}	300	A
Typical Thermal Resistance Junction to Case	$R_{\theta JC}$	2.8	/W
Junction Temperature Range	T_J	150	
Storage Temperature Range	T_J		

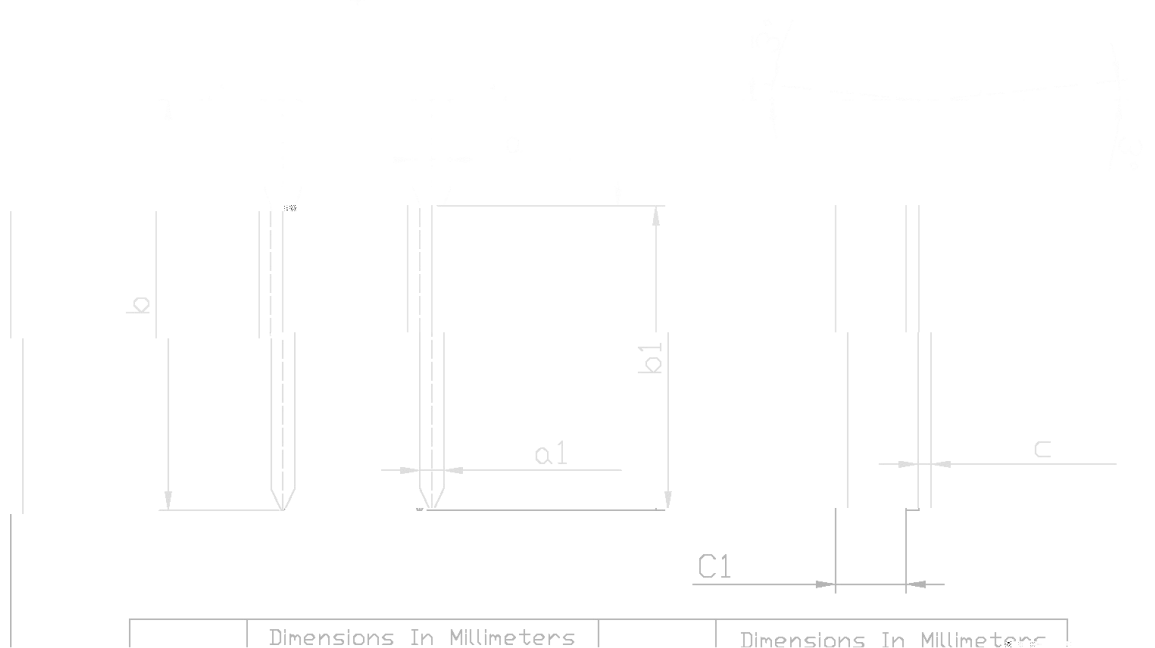
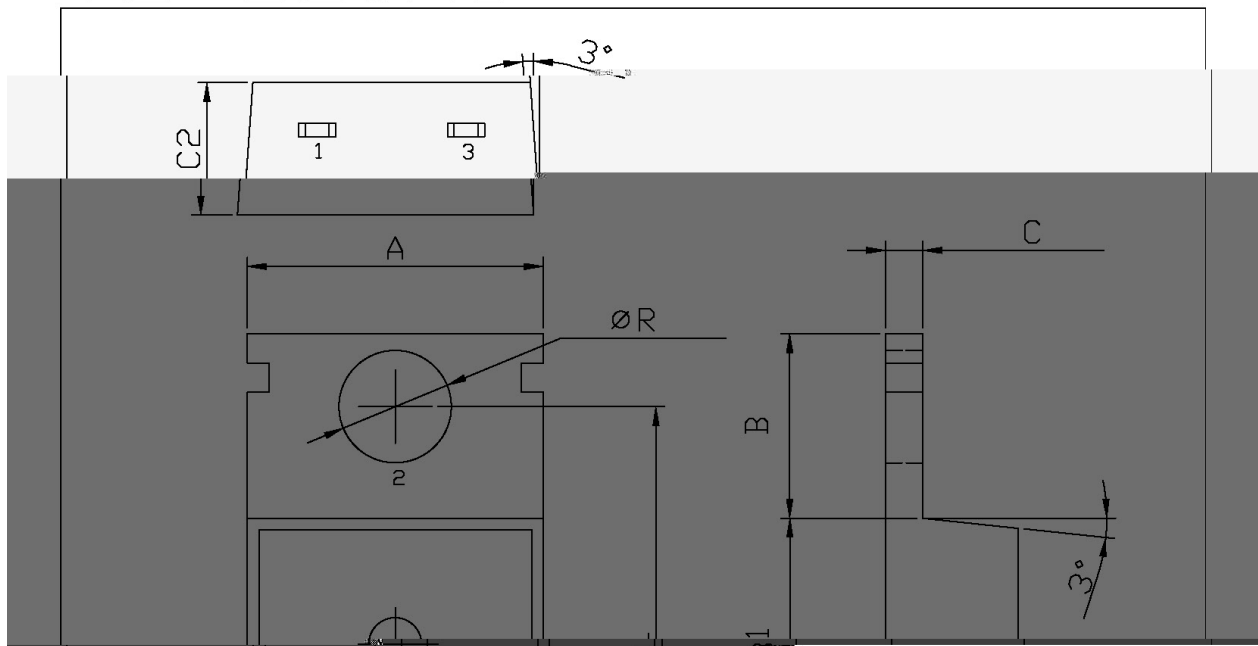
/ Electrical Characteristic Curve



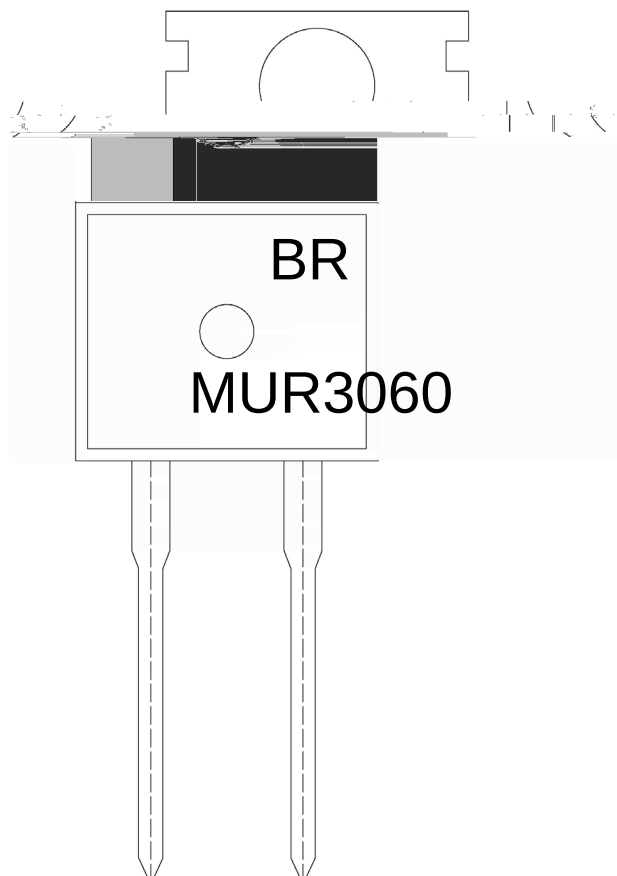
/ Package Dimensions

TO-220AC

Unit:mm



/ Marking Instructions



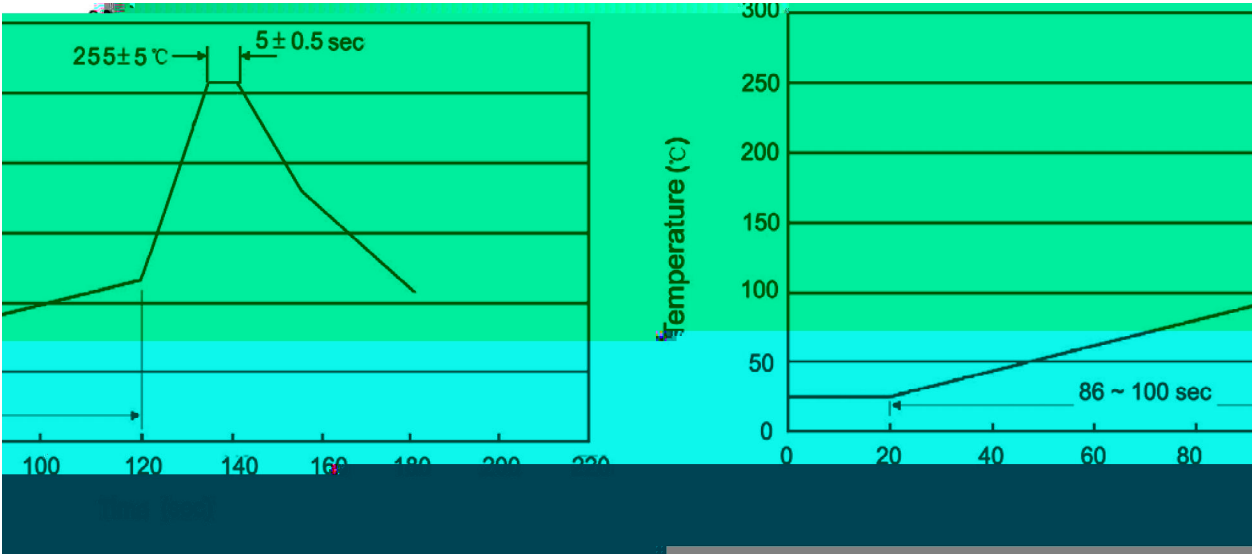
Note:

BR: Company Code

MUR3060 Product Type.

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- 1

25 150

60 90sec;
- 2

255 5

5 0.5sec;
- 3

2 10

/sec.
- 1.Preheating:25~150

,

Time:60~90sec.
- 2.Peak Temp.:255 5

,

Duration:5 0.5sec.
3. Cooling Speed: 2~10

/sec.

/ Resistance to Soldering Heat Test Conditions

270 5

10 1 sec.

Temp.:270±5

Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type	Units 包装数量		Dimension 包装尺寸 (unit: mm ³)
封装形式	只 袋	袋 盒	只 盒